

## Dimensions (mm)

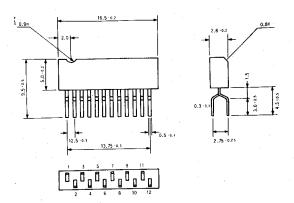


Fig. 1

### Features

- Rated output power of 230mW with a supply voltage of 3V (R<sub>L</sub> = 4Ω, THD = 10%)
- Partially built-in ALC circuit enables ALC operation at voltages even below
- A built-in protective circuit prevents destruction by excessive voltages and is able to withstand misuse of AC adaptors in the range 6~15V.
- 4. Housed in a compact 12-pin formed package
- 5. Prevention of pop noise occurring on power application has been included.
- 6. High ripple rejection ratio

# **Applications**

- 1. Microcassette tape recorders
- 2. 3V Mini-cassette tape recorders
- 3. Ultra-thin radios

developed for use in 3V tape recorders. It can be used in OTL configuration at low voltages and, when compared with OT type circuits, provides stable feedback and excellent distortion versus frequency characteristics. In addition, it requires few externally connected components thus contributing to the compact design and simplification of electronic tape recorders. The internal circuit of the BA515 makes use of the OTL configuration, a system thought previously to be unsuited to 3V equipment, and provides a compensating circuit for operatin at low voltages, thereby achieving a starting voltage of 1.5V or less. To establish the ALC operating characteristics for recording, a partially built-in ALC circuit is used to apply ALC control for even recording output in the 0.4V range. Thus, for operation below even 2V, sufficient recording and playback characteristics are achievable, enabling the drive of  $4\Omega$  speakers with the rated output power. The output of 230mW (3V operations/4 $\Omega$ load, EIAJ) is sufficient to drive speakers, and the pop noise occurring upon power application, motor noise and supply ripple rejection characteristics have been taken into consideration in this design. To allow use at low voltages and in particular AC adaptors where misuse can apply excessive voltages, protection from such conditions is provided by a special built-in protective circuit. In addition, the compact, 12-pin zig-zag package is formed to increase mounting density.

The BA515 is a monolithic integrated circuit consisting of an OTL power amplifier

# Circuit Diagram

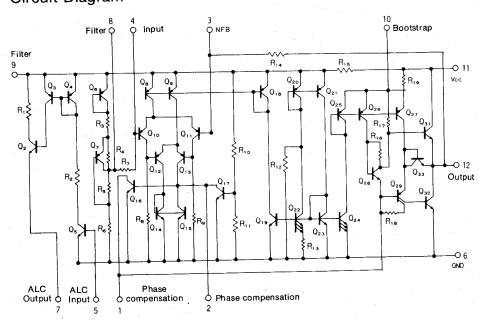


Fig. 2



#### Absolute Maximum Ratings (T<sub>a</sub> = 25°C)

Parameter	Symbol	Limits	Unit	
Supply voltage	Vcc	15	V ,	
Power dissipation	Pd	500*	mW	
Operating temperature	Topr	10~+65	°C	
Storage temperature	T <sub>stg</sub>	-30~+125	°C	

<sup>\*</sup> Derating is done at  $5mW/^{\circ}C$  for operation above  $T_a = 25^{\circ}C$ .

## Electrical Characteristics ( $T_a = 25^{\circ}C$ , $V_{CC} = 3V$ , $R_L = 4\Omega$ , f = 1kHz)

Parameter	Symbol	Min	Тур	Max	Unit	Conditions	Test circuit
Quiescent current	ΙQ		12	<del>-</del>	mA		Fig. 13
Closed-loop voltage gain	Gvc	33	36	39	dB	$R_{NF} = 270\Omega$	Fig. 13
Rated output power	Pour	180	230		mW	THD = 10%	Fig. 13
Total harmonic distortion	THD	. —	0.4	2.0	%	P <sub>O</sub> = 50mW	Fig. 13
Output noise voltage	$V_{NO}$	. —	0.1	1.0	mVrms	$R_g = 0\Omega$	Fig. 13
Input resistance	R <sub>IN</sub>	10	20	_	kΩ		Fig. 13
Ripple rejection ratio	RR	25	40		dB	$R_g = 0\Omega$ , $f = 100Hz$	Fig. 13
Starting voltage	Vs	1.5		_	, V	V <sub>O</sub> = 50mV	Fig. 13
ALC Transistor base current	IBOFF		-	1	μΑ	S <sub>1</sub> = 2	Fig. 13
ALC Transistor base current	I <sub>BON</sub>	1.0		-	mA	S <sub>1</sub> = 1	Fig. 13

## **Electrical Characteristic Curves**

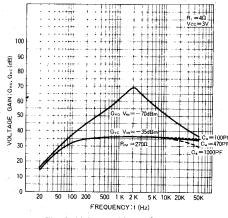


Fig. 3 Voltage gain vs. frequency

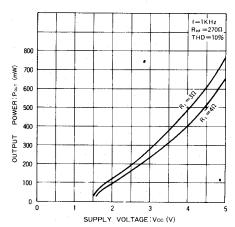


Fig. 6 Output power vs. supply voltage

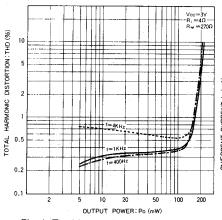


Fig. 4 Total harmonic distortion vs. output power

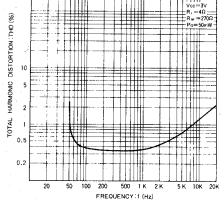


Fig. 7 Total harmonic distortion vs. frequency

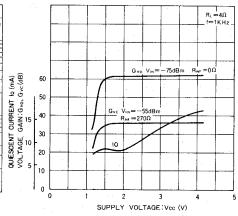


Fig. 5 Quiescent current and voltage gain vs. supply voltage

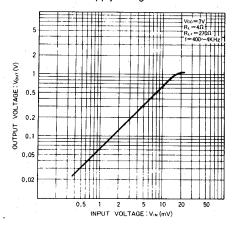


Fig. 8 Output voltage vs. input voltage